Low Voltage Comparators

The NCS2200 Series is an industry first sub-one volt, low power comparator family. These devices consume only 10 μ A of supply current. They are guaranteed to operate at a low voltage of 0.85 V which allows them to be used in systems that require less than 1.0 V and are fully operational up to 6.0 V which makes them convenient for use in both 3.0 V and 5.0 V systems. Additional features include no output phase inversion with overdriven inputs, internal hysteresis, which allows for clean output switching, and rail-to-rail input and output performance. The NCS2200 Series is available in the tiny SOT-23-5 and SOT-23-6 package. There are eight options featuring two industry standard pinouts. Additionally, the NCS2200 and NCS2202 are available in the SC70-5 package. The NCS2200 is also available in the tiny DFN 2x2.2 package. The NCS2200A is available in UDFN 1.2x1.0 package. (Table 1)

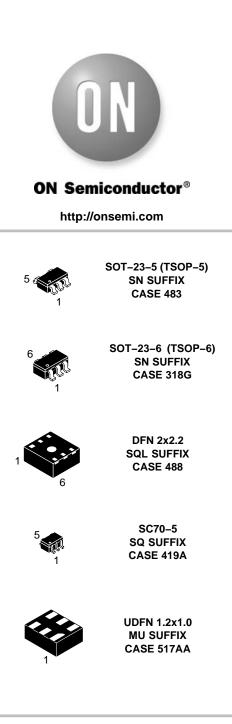
The NCS2201/3 Series in the SOT–23–6 package features an enable function, which can be externally controlled. When the enable pin is pulled low (output tri–state mode), current consumption is typically 0.3 μ A. This allows the user to implement these devices in power sensitive applications such as portable electronics.

Features

- Operating Voltage of 0.85 V to 6.0 V
- Rail-to-Rail Input/Output Performance
- Low Supply Current of 10 μA
- No Phase Inversion with Overdriven Input Signals
- Glitchless Transitioning in or out of Tri-State Mode
- Complementary or Open Drain Output Configuration
- Available with the Enable Function
- Internal Hysteresis
- Propagation Delay of 1.1 µs
- Pb–Free Packages are Available

Typical Applications

- Single Cell NiCd/NiMH Battery Powered Applications
- Cellular Telephones
- Alarm and Security Systems
- Personal Digital Assistants



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 13 of this data sheet.

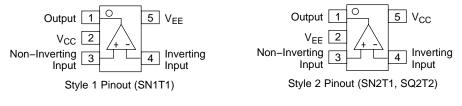
DEVICE MARKING INFORMATION

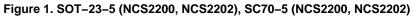
See general marking information in the device marking section on page 14 of this data sheet.

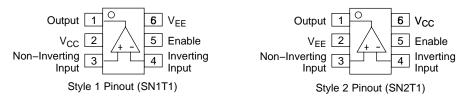
Table 1. Comparator Selector Guide

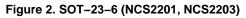
Output Type	Device	Package	Pinout Style
Complementary	NCS2200SN1T1	SOT-23-5	1
Complementary	NCS2200SN2T1	SOT-23-5	2
Complementary	NCS2200SQ2T2	SC70-5	2
Complementary, Enable	NCS2201SN1T1	SOT-23-6	1
Complementary, Enable	NCS2201SN2T1	SOT-23-6	2
Open Drain	NCS2202SN1T1	SOT-23-5	1
Open Drain	NCS2202SQ1T2	SC70-5	1
Open Drain	NCS2202SN2T1	SOT-23-5	2
Open Drain	NCS2202SQ2T2	SC70–5	2
Open Drain, Enable	NCS2203SN1T1	SOT-23-6	1
Open Drain, Enable	NCS2203SN2T1	SOT-23-6	2
Complementary	NCS2200SQLT1	DFN, 2x2.2	N/A
Complementary	NCS2200AMUT1	UDFN, 1.2x1.0	N/A

PIN CONNECTIONS











MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range (V _{CC} to V _{EE})	VS	6.0	V
Non-inverting/Inverting Input to V _{EE}	-	-0.2 to (V _{CC} + 0.2)	V
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature	T _A	-40 to +105	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Output Short Circuit Duration Time (Note 1)	t _S	Indefinite	S
ESD Tolerance (Note 2) NCS2200/2201 Human Body Model Machine Model NCS2202/NCS2203 Human Body Model Machine Model NCS2200A Human Body Model Machine Model	_	2000 200 1000 200 1900 200	V
Thermal Resistance, Junction-to-Ambient TSOP-5 DFN (Note 3) SC70-5 UDFN	R _{θJA}	238 215 283 350	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The maximum package power dissipation limit must not be exceeded.

$$P_{D} = \frac{T_{J}(max) - T_{A}}{R_{\theta,JA}}$$

2. ESD data available upon request.

3. For more information, refer to application note, AND8080/D.

		N	ICS2200 Serie	s	
Characteristics	Symbol	Min	Тур	Max	Unit
Input Hysteresis $T_A = 25^{\circ}C$	V _{HYS}	2.0	8.0	20	mV
Input Offset Voltage	V _{IO}				mV
$V_{CC} = 0.85 V$ $T_A = 25^{\circ}C$		-10	0.5	+10	
$T_{A} = 23 \text{ C}$ $T_{A} = -40^{\circ}\text{C} \text{ to } 105^{\circ}\text{C}$		-12	-	+12	
$V_{CC} = 3.0 V$					
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-6.0 -8.0	0.5	+6.0 +8.0	
$V_{\rm CC} = 6.0 \text{ V}$		-8.0	_	+0.0	
$T_A = 25^{\circ}C$		-5.0	0.5	+5.0	
$T_A = -40^{\circ}C$ to $105^{\circ}C$		-7.0	-	+7.0	
Common Mode Voltage Range	V _{CM}	-	V_{EE} to V_{CC}	-	V
Output Leakage Current (NCS2202/NCS2203) V_{CC} = 6.0 V	I _{LEAK}	-	3.3	-	nA
Output Short–Circuit Sourcing or Sinking (Vout = GND)	I _{SC}	-	70	-	mA
Common Mode Rejection Ratio $V_{CM} = V_{CC}$	CMRR	53	65	-	dB
Input Bias Current	I _{IB}	-	1.0	-	pА
Power Supply Rejection Ratio ΔV_S = 2.575 V	PSRR	45	55	-	dB
Supply Current	Icc				μA
$V_{CC} = 0.85 V$ $T_A = 25^{\circ}C$		_	10	15	
$T_A = -40^{\circ}C$ to $105^{\circ}C$			-	17	
$V_{CC} = 3.0 V$			10	45	
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to $105^{\circ}C$		_	10 -	15 17	
$V_{CC} = 6.0 V$					
$T_{A} = 25^{\circ}C$		-	10	15	
$T_{A} = -40^{\circ}C \text{ to } 105^{\circ}C$	M		_	17	V
Output Voltage High (NCS2200/NCS2201) $V_{CC} = 0.85$ V, I _{source} = 0.5 mA	V _{OH}				V
$T_A = 25^{\circ}C$		V _{CC} – 0.2	V _{CC} – 0.10	-	
$T_{A} = -40^{\circ}C \text{ to } 105^{\circ}C$		V _{CC} – 0.225	-		
$V_{CC} = 3.0 \text{ V}, \text{ I}_{source} = 3.0 \text{ mA}$ $T_A = 25^{\circ}\text{C}$		V _{CC} – 0.2	V _{CC} – 0.12	_	
$T_A = -40^{\circ}C$ to $105^{\circ}C$		V _{CC} – 0.25	-		
$V_{CC} = 6.0 \text{ V}, \text{ I}_{source} = 5.0 \text{ mA}$			V _{CC} – 0.12		
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		V _{CC} – 0.2 V _{CC} – 0.25	V _{CC} – 0.12 –	_	
Output Voltage Low	V _{OL}				V
V _{CC} = 0.85 V, I _{sink} = 0.5 mA					
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-	V _{EE} + 0.10	V _{EE} + 0.2 V _{EE} + 0.225	
$V_{CC} = 3.0 \text{ V}, I_{sink} = 3.0 \text{ mA}$			_	VEE + 0.223	
$T_A = 25^{\circ}C$		-	V _{EE} + 0.12		
$T_A = -40^{\circ}C$ to $105^{\circ}C$ $V_{CC} = 6.0$ V, $I_{sink} = 5.0$ mA			-	V _{EE} + 0.25	
$T_{A} = 25^{\circ}C$		-	V _{EE} + 0.12	V _{EE} + 0.2	
$T_A = -40^{\circ}C$ to $105^{\circ}C$			-	V _{EE} + 0.25	
Propagation Delay 20 mV Overdrive, $C_L = 15 \text{ pF}$	+		0.7		μs
	t _{PHL} t _{PLH}	-	0.7 1.1	-	
Output Fall Time V_{CC} = 6.0 V, C _L = 50 pF	t _{FALL}	_	20	_	ns
Output Rise Time $V_{CC} = 6.0 \text{ V}, C_L = 50 \text{ pF}$	t _{RISE}	_	16	_	ns
Powerup Time	t _{PU}	_	35	_	μS

ELECTRICAL CHARACTERISTICS (For all values $V_{CC} = 0.85$ V to 6.0 V, $V_{EE} = 0$ V, $T_A = 25^{\circ}C$, unless otherwise noted.) (Note 4)

4. The limits over the extended temperature range are guaranteed by design only.

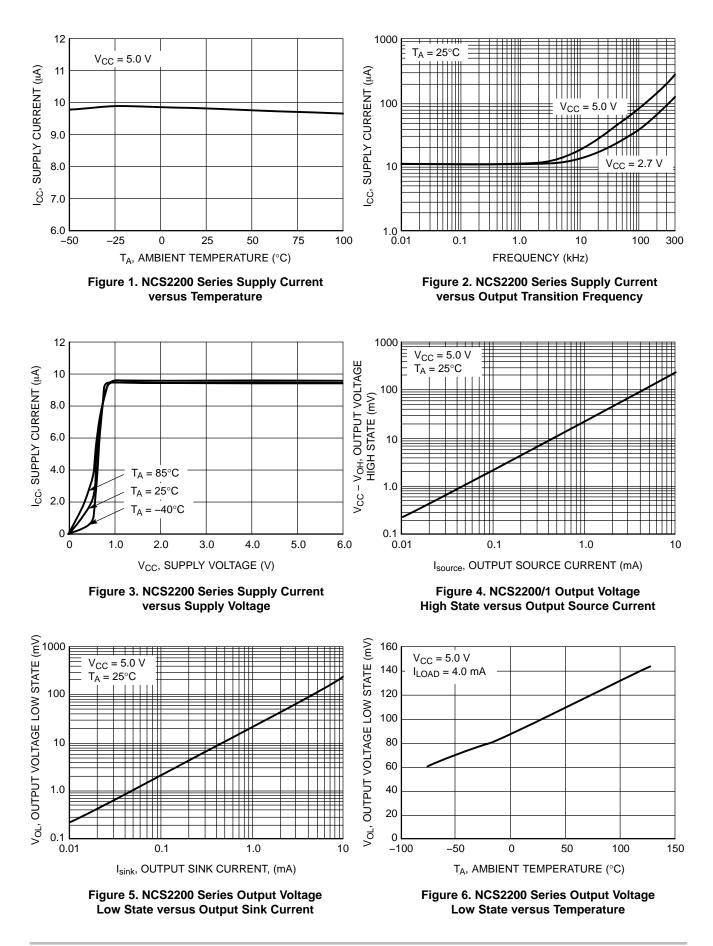
			NCS2200A			
Characteristics	Symbol	Min	Тур	Max	Unit	
Input Hysteresis $T_A = 25^{\circ}C$	V _{HYS}	2.0	4.5	20	mV	
Input Offset Voltage	V _{IO}				mV	
$V_{CC} = 0.85 V$		10	0.5	. 10		
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		-10 -12	0.5	+10 +12		
$V_{CC} = 3.0 V$		12		112		
$T_A = 25^{\circ}C$		-6.0	0.5	+6.0		
$T_A = -40^\circ C$ to $105^\circ C$		-8.0	-	+8.0		
$V_{CC} = 6.0 V$ $T_A = 25^{\circ}C$		-5.0	0.5	+5.0		
$T_A = -40^{\circ}C$ to $105^{\circ}C$		-7.0	_	+7.0		
Common Mode Voltage Range	V _{CM}	-	V_{EE} to V_{CC}	-	V	
Output Short–Circuit Sourcing or Sinking (Vout = GND)	I _{SC}	-	60	-	mA	
Common Mode Rejection Ratio $V_{CM} = V_{CC}$	CMRR	53	70	-	dB	
Input Bias Current	Ι _{IB}	-	1.0	-	pА	
Power Supply Rejection Ratio ΔV_S = 2.575 V	PSRR	45	80	_	dB	
Supply Current	I _{CC}				μA	
$V_{CC} = 0.85 V$ $T_A = 25^{\circ}C$		_	7.5	15		
$T_{A} = -40^{\circ}C$ to $105^{\circ}C$			_	17		
$V_{CC} = 3.0 V$						
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to $105^{\circ}C$		-	8.0	15 17		
$V_{\rm CC} = 6.0 \text{ V}$				17		
$T_A = 25^{\circ}C$		-	9.0	15		
$T_A = -40^{\circ}C$ to $105^{\circ}C$			-	17		
Output Voltage High	V _{OH}				V	
$V_{CC} = 0.85$ V, $I_{source} = 0.5$ mA $T_A = 25^{\circ}C$		V _{CC} – 0.25	V _{CC} – 0.10	_		
$T_{A} = -40^{\circ}$ C to 105°C		$V_{CC} - 0.275$	-			
$V_{CC} = 3.0 \text{ V}, \text{ I}_{\text{source}} = 3.0 \text{ mA}$						
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to 105°C		V _{CC} – 0.3 V _{CC} – 0.35	V _{CC} – 0.12	-		
$V_{CC} = 6.0 \text{ V}, I_{source} = 5.0 \text{ mA}$		VCC - 0.33	_			
$T_A = 25^{\circ}C$			V _{CC} – 0.12	-		
$T_A = -40^{\circ}C$ to $105^{\circ}C$		V _{CC} – 0.35	-			
Output Voltage Low	V _{OL}				V	
$V_{CC} = 0.85 \text{ V}, I_{sink} = 0.5 \text{ mA}$ $T_A = 25^{\circ}\text{C}$		_	Vee + 0.10	V _{EE} + 0.25		
$T_{A} = -40^{\circ}C$ to $105^{\circ}C$			_	V _{EE} + 0.275		
$V_{CC} = 3.0 \text{ V}, \text{ I}_{sink} = 3.0 \text{ mA}$						
$T_A = 25^{\circ}C$ $T_A = -40^{\circ}C$ to $105^{\circ}C$		-	V _{EE} + 0.12 -	V _{EE} + 0.3 V _{EE} + 0.35		
$V_{CC} = 6.0 \text{ V}, I_{sink} = 5.0 \text{ mA}$						
$T_A = 25^{\circ}C$		-	V _{EE} + 0.12			
$T_A = -40^{\circ}C$ to $105^{\circ}C$			-	V _{EE} + 0.35		
Propagation Delay 20 mV Overdrive, $C_L = 15 \text{ pF}$	+		0.5		μs	
	t _{PHL} t _{PLH}	_	0.5 0.5	_		
Output Fall Time $V_{CC} = 6.0 \text{ V}, C_L = 50 \text{ pF}$ (Note 6)	t _{FALL}	_	20	-	ns	
					-	

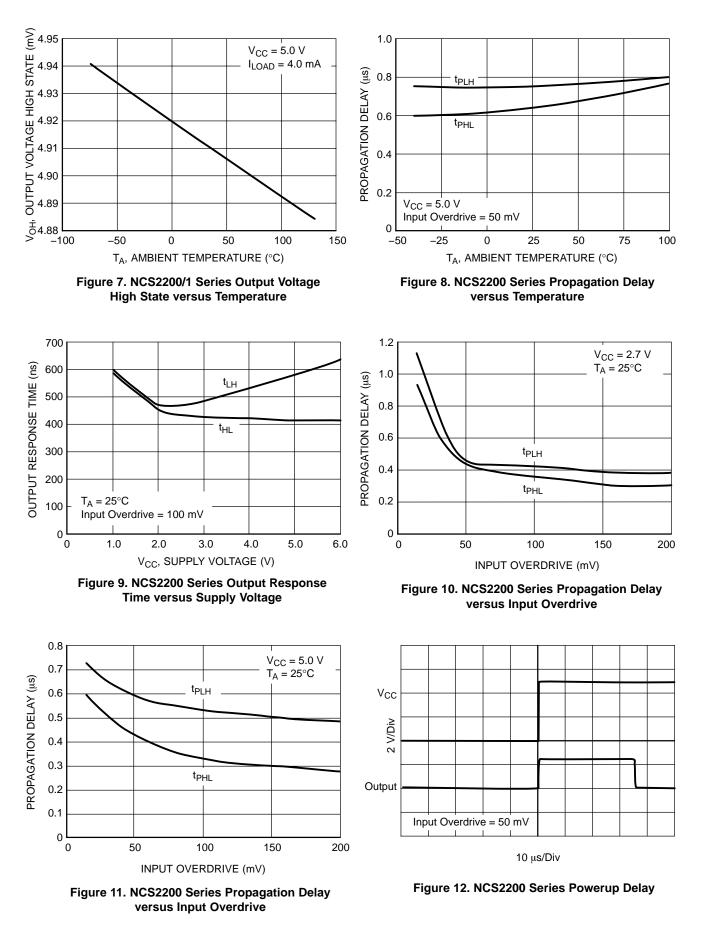
The limits over the extended temperature range are guaranteed by design only.
 Input signal: 1 kHz, squarewave signal with 10 ns edge rate.

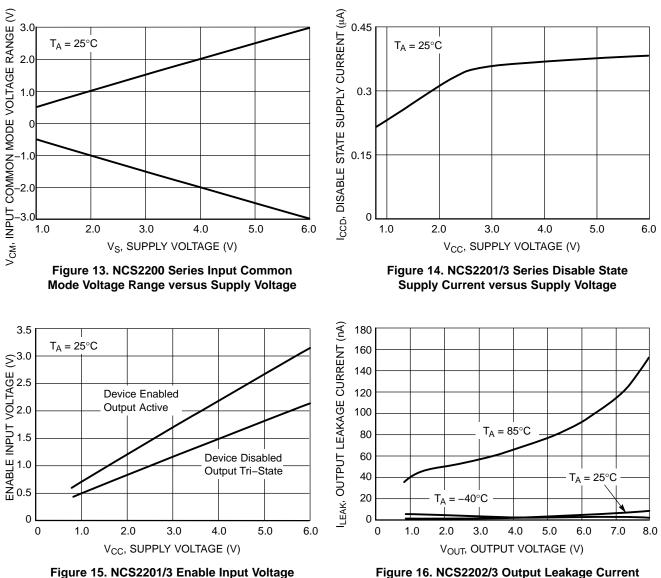
ENABLE FUNCTION ELECTRICAL CHARACTERISTICS (NCS2201/NCS2203 only) (For all values $V_{CC} = 6.0$ V, $V_{EE} = 0$ V, $T_A = 25^{\circ}$ C, unless otherwise noted.) (Note 7)

Characteristics	Symbol	Min	Тур	Max	Unit
Enable Voltage Threshold Input Voltage Increasing, Device Enabled Input Voltage Decreasing, Device Disabled	V _{EN(HIGH)} V _{EN(LOW)}	_ 2.0	3.2 2.2	4.0 -	V
Enable Hysteresis	V _{ENHYS}	-	1.0	-	V
Enable Pullup Current	I _{EN}	-	100	200	nA
Disable State Supply Current	I _{CCD}	-	300	600	nA
Enable Input to Output Propagation Delay Input Voltage Increasing, Device Enabled Input Voltage Decreasing, Device Disabled	t _{EN(ON)} t _{EN(OFF)}		82 0.5		μs

7. The limits over the extended temperature range are guaranteed by design only.







versus Supply Voltage

Figure 16. NCS2202/3 Output Leakage Current versus Output Voltage

OPERATING DESCRIPTION

The NCS2200 Series is an industry first sub-one volt, low power comparator family. This series is designed for rail-to-rail input and output performance. These devices consume only 10 µA of supply current while achieving a typical propagation delay of 1.1 µs at a 20 mV input overdrive. Figures 10 and 11 show propagation delay with various input overdrives. This comparator family is guaranteed to operate at a low voltage of 0.85 V up to 6.0 V. This is accomplished by the use of a modified analog CMOS process that implements depletion MOSFET devices. The common-mode input voltage range extends 0.1 V beyond the upper and lower rail without phase inversion or other adverse effects. This series is available in the SOT-23-5 and SOT-23-6 package. Additionally, the NCS2200 device is available in the tiny DFN 2x2.2 package and the SC70-5 package. NCS2200A is available in UDFN package.

The SOT-23-6 features the enable function, which can be externally controlled. This feature allows significantly lower current consumption of 0.3 μ A. This makes the devices suitable for implementation in power sensitive applications such as portable electronics. The enable

function is active high when connected to the V_{CC} pin. When the enable pin is driven low (device disabled), output tri–state mode is activated. The device will remain in this mode and will not respond to any changes at the inputs of the comparator. In order to pull the device out of tri–state mode, the enable upper voltage threshold must be met. Figure 15 shows the enable input voltage required to either enable or disable the device, with a variance in supply voltage. In addition, these devices have a typical internal hysteresis of ± 8.0 mV. This allows for greater noise immunity and clean output switching.

Output Stage

The NCS2200/1 has a complementary P and N Channel output stage that has capability of driving a rail-to-rail output swing with a load ranging up to 5.0 mA. It is designed such that shoot-through current is minimized while switching. This feature eliminates the need for bypass capacitors under most circumstances.

The NCS2202/3 has an open drain N–channel output stage that can be pulled up to 6.0 V (max) with an external resistor. This facilitates mixed voltage system applications.

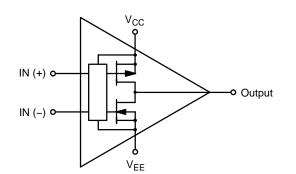


Figure 17. NCS2200/1SNxT1/NCS2200A Complementary Output Configuration

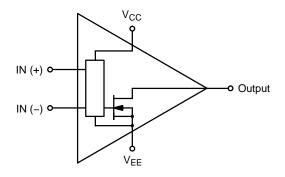
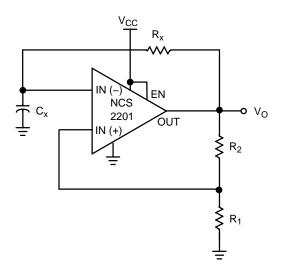


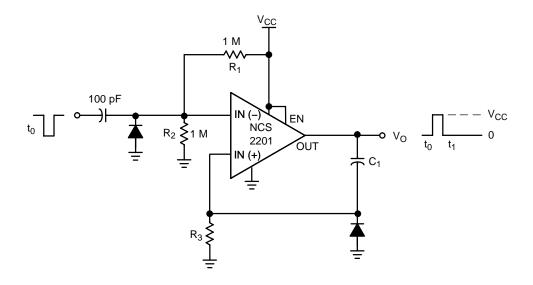
Figure 18. NCS2202/3SNxT1 Open Drain Output Configuration



The oscillation frequency can be programmed as follows:

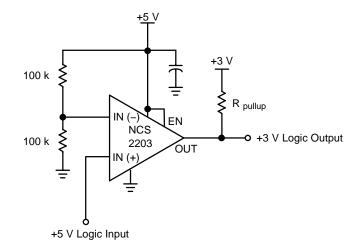
$$f = \frac{1}{T} = \frac{1}{2.2 R_X C_X}$$

Figure 19. Schmitt Trigger Oscillator



The resistor divider R_1 and R_2 can be used to set the magnitude of the input pulse. The pulse width is set by adjusting C_1 and $\mathsf{R}_3.$

Figure 20. One-Shot Multivibrator



This circuit converts 5 V logic to 3 V logic. Using the NCS2202/3 allows for full 5 V logic swing without creating overvoltage on the 3 V logic input.



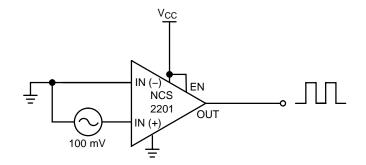


Figure 22. Zero-Crossing Detector

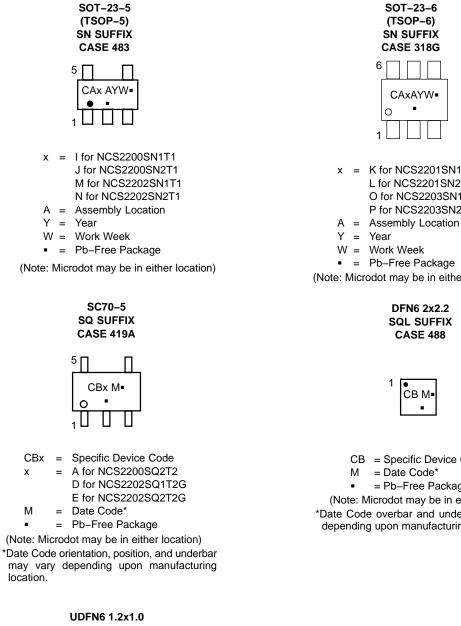
ORDERING INFORMATION

Device	Pinout Style	Output Type	Package	Shipping [†]
NCS2200AMUT1G	N/A	Complementary	UDFN (Pb-Free)	3000 / Tape & Reel
NCS2200SN1T1	1	Complementary	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2200SN1T1G	1	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SN2T1	2	Complementary	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2200SN2T1G	2	Complementary	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2200SQ2T2	2	Complementary	SC70–5	3000 / Tape & Reel
NCS2200SQ2T2G	2	Complementary	SC70–5 (Pb–Free)	3000 / Tape & Reel
NCS2200SQLT1	N/A	Complementary	DFN, 2x2.2	3000 / Tape & Reel
NCS2200SQLT1G	N/A	Complementary	DFN, 2x2.2 (Pb-Free)	3000 / Tape & Reel
NCS2201SN1T1	1	Complementary, Enable	SOT-23-6 (TSOP-6)	3000 / Tape & Reel
NCS2201SN1T1G	1	Complementary, Enable	SOT-23-6 (TSOP-6) (Pb-Free)	3000 / Tape & Reel
NCS2201SN2T1	2	Complementary, Enable	SOT-23-6 (TSOP-6)	3000 / Tape & Reel
NCS2201SN2T1G	2	Complementary, Enable	SOT-23-6 (TSOP-6) (Pb-Free)	3000 / Tape & Reel
NCS2202SN1T1	1	Open Drain	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2202SN1T1G	1	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ1T2G	1	Open Drain	SC70–5 (Pb–Free)	3000 / Tape & Reel
NCS2202SN2T1	2	Open Drain	SOT-23-5 (TSOP-5)	3000 / Tape & Reel
NCS2202SN2T1G	2	Open Drain	SOT-23-5 (TSOP-5) (Pb-Free)	3000 / Tape & Reel
NCS2202SQ2T2G	2	Open Drain	SC70–5 (Pb–Free)	3000 / Tape & Reel
NCS2203SN1T1	1	Open Drain, Enable	SOT-23-6 (TSOP-6)	3000 / Tape & Reel
NCS2203SN1T1G	1	Open Drain, Enable	SOT-23-6 (TSOP-6) (Pb-Free)	3000 / Tape & Reel
NCS2203SN2T1	2	Open Drain, Enable	SOT-23-6 (TSOP-6)	3000 / Tape & Reel
NCS2203SN2T1G	2	Open Drain, Enable	SOT-23-6 (TSOP-6) (Pb-Free)	3000 / Tape & Reel

This device contains 93 active transistors.

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MARKING DIAGRAMS



MU SUFFIX CASE 517AA

х



(Top View)

= Specific Device Code S

= Pb-Free Package



- x = K for NCS2201SN1T1 L for NCS2201SN2T1 O for NCS2203SN1T1 P for NCS2203SN2T1
- = Pb-Free Package

(Note: Microdot may be in either location)





CB = Specific Device Code

- = Pb-Free Package

(Note: Microdot may be in either location) *Date Code overbar and underbar may vary depending upon manufacturing location.

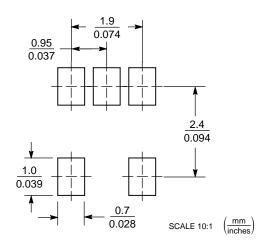
SOT-23-5 / TSOP-5 / SC59-5 **SN SUFFIX** PLASTIC PACKAGE CASE 483-02 **ISSUE F**

NOTE 5 D 5X \oplus 0.20 C A B 2X 🛆 0.10 T ¥ 2X 🗀 0.20 T 5 в S A ШШ L DETAIL Z G С SEATING PLANE □ 0.05 (Ť)

- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.
- BURRS. 5.
- OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

	MILLIN	IETERS
DIM	MIN	MAX
Α	3.00	BSC
В	1.50	BSC
С	0.90	1.10
D	0.25	0.50
G	0.95	BSC
н	0.01	0.10
J	0.10	0.26
κ	0.20	0.60
L	1.25	1.55
м	0 °	10 °
S	2.50	3.00

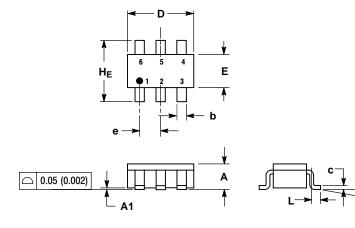
SOLDERING FOOTPRINT*



DETAIL Z

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOT-23-6 / TSOP-6 / SC59-6 **SN SUFFIX** CASE 318G-02 ISSUE S

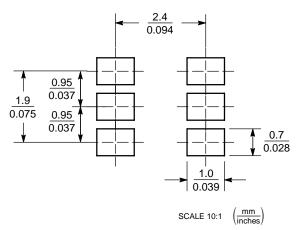


NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

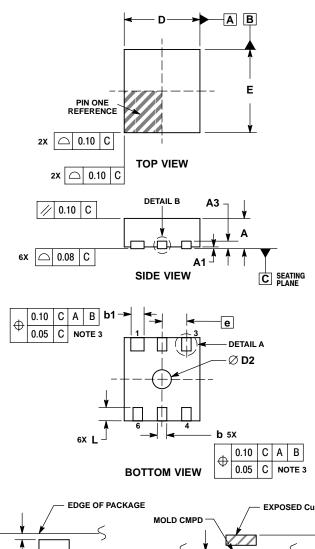
	м	MILLIMETERS			IILLIMETERS INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
Α	0.90	1.00	1.10	0.035	0.039	0.043		
A1	0.01	0.06	0.10	0.001	0.002	0.004		
b	0.25	0.38	0.50	0.010	0.014	0.020		
С	0.10	0.18	0.26	0.004	0.007	0.010		
D	2.90	3.00	3.10	0.114	0.118	0.122		
E	1.30	1.50	1.70	0.051	0.059	0.067		
е	0.85	0.95	1.05	0.034	0.037	0.041		
L	0.20	0.40	0.60	0.008	0.016	0.024		
HE	2.50	2.75	3.00	0.099	0.108	0.118		
θ	0°	-	10°	0°	-	10°		

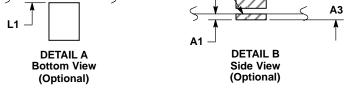
SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DFN6, 2x2.2 SQL SUFFIX CASE 488-03 **ISSUE G**



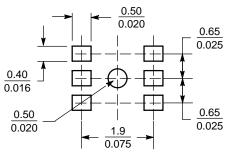


NOTES:

- IDIRESIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30mm FROM TERMINAL.
 COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
 TERMINAL & MAY HAVE MOLD COMPOUND MATERIAL AL ONG SIDE EDGE
- MATERIAL ALONG SIDE EDGE. 6. DETAILS A AND B SHOW OPTIONAL VIEWS FOR END OF TERMINAL LEAD AT EDGE OF PACKAGE AND SIDE EDGE OF PACKAGE.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.80	0.90	1.00	
A1	0.00	0.03	0.05	
A3		0.20 REF		
b	0.20	0.25	0.30	
b1	0.30	0.35	0.40	
D		2.00 BSC		
D2	0.40	0.50	0.60	
Е		2.20 BSC		
е	0.65 BSC			
Ĺ	0.30	0.35	0.40	
L1	0.00	0.05	0.10	

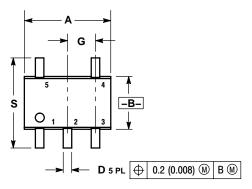
SOLDERING FOOTPRINT*

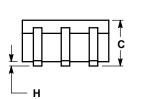


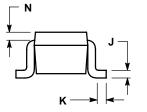
SCALE 10:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SC70-5/SC88A (SOT-353) SQ SUFFIX CASE 419A-02 ISSUE J





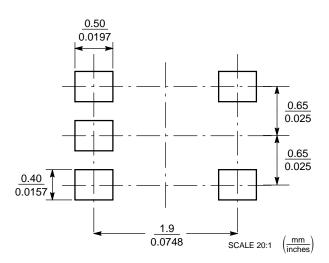


NOTES:

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. 419A-01 OBSOLETE. NEW STANDARD 419A-02. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

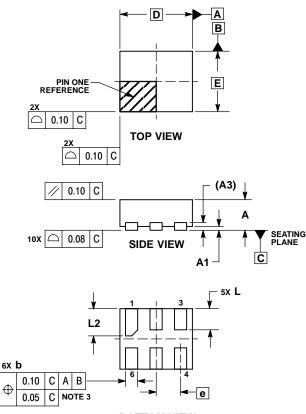
	INC	HES	MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026	BSC	0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
Κ	0.004	0.012	0.10	0.30
Ν	0.008 REF		0.20	REF
S	0.079	0.087	2.00	2.20





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

UDFN6, 1.2x1.0, 0.4P CASE 517AA ISSUE A



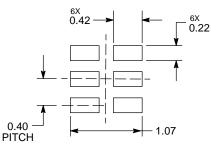
BOTTOM VIEW

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.
- PAD AS WELL AS THE TERMINALS.

	MILLIMETERS				
DIM	MIN	MAX			
Α	0.45	0.55			
A1	0.00	0.05			
A3	0.127 REF				
b	0.15	0.25			
D	1.00	BSC			
Е	1.20	BSC			
е	0.40 BSC				
L	0.30	0.40			
L2	0.40	0.50			

MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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